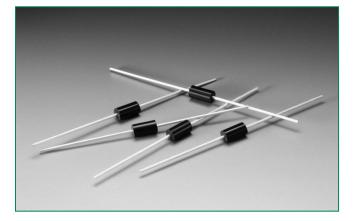
Teccor[®] brand Thyristors Multipulse[™]SIDACs



RoHS

Kxxx1G Series



Schematic Symbol



Applications

Typical application circuit presented in Figure 10 of this data sheet (Typical Metal Halide Ignitor Circuit).

Description

The Multipulse[™] SIDAC is a voltage switch used in Metal-Halide lamp ignition circuits as well as High Pressure Sodium lamp ignition circuits for outdoor street and area lighting. This robust solid state switch is designed to handle lamp igniter applications requiring operation at ambient temperatures up to 90°C where igniter circuit components can raise SIDAC junction temperature up to 125°C, especially when the lamp element is removed or ruptured. Its excellent commutation time (t_{COMM}) makes this robust product best suited for producing multiple pulses in each half cycle of 50/60 Hz line voltage. The Multipulse[™] SIDAC is offered in DO-15 axial leaded package.

Kxxx1G SIDAC has a repetitive off-state blocking voltage (V_{DRM}) of 180V to 270V minimum depending actual device type. Blocking capability is ensured by glass passivated junctions for best reliability. Package is epoxy encapsulation with tin-plated copper alloy leads.

Features

- RoHS Compliant
- Triggering Voltage of 200 to 380V

AC circuit oriented

Symbol	Parameters	Test Conditions	Min	Max	Unit
		K2201G	200	230	
V	Breakover/Trigger Voltage	K2401G	220	250	V
V _{BO}	breakover/ mgger voltage	K2501G	240	280	v
		K3601G	340	380	
		K2201G	180		
V _{DRM}	Repetitive Peak Off-State Voltage	K2401G	190		V
DRIVI		K2501G	200		
		K3601G 50/60Hz	270		
I _{T(RMS)}	On-State RMS Current, T _J < 125°C	Sine Wave		1	A
		50/60Hz		100 T/D	
I _H	Dynamic Holding Current, R=100 Ω	Sine Wave		120 TYP	mA
	$(\lambda I - \lambda I)$				
R _s	Switching Resistance, $R_s = \frac{(V_{BO} - V_s)}{(I_s - I_{PO})}$	50/60Hz Sine Wave	100		Ω
0	$(I_{\rm S} - I_{\rm BO})$	Sille VVave			
+	Commutation Time T ₁ < 125°C	See test circuit and		100 1	11000
t _{comm}		waveform in Figure 9		100	µsec
1	Breakover Current	50/60Hz		10	uA
BO		Sine Wave			
I _{tsm}	Non-repetitive 1 cycle On-State peak value	60Hz		20.0	A
	Critical Data of Diag of Ore State Comment	50Hz		16.7	A /
di/dt	Critical Rate of Rise of On-State Current			150	A/µsec
dv/dt	Critical Rate of Rise of Off-State Voltage			1500	V/µsec
T _s	Storage Temperature Range		-40	+125	°C
T _J	Max Operating Junction Temperature		-40	+125	°C
R _{ejl}	Thermal Resistance	Junction to lead		18	°C/W

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Revised: 03/25/16



Figure 1: Characteristics

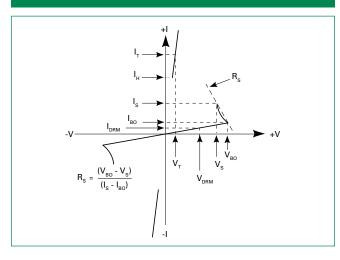


Figure 3: Power Dissipation (Typical) vs. On-State Current

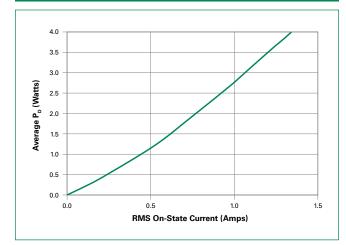


Figure 5: Pulse On-State Current Rating

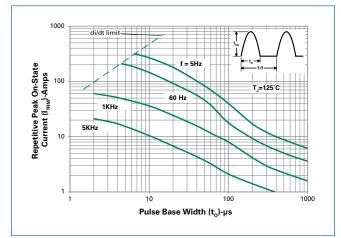


Figure 2: Maximum Allowable Lead/Tab Temperature vs. On-State Current

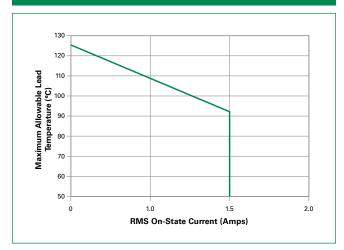


Figure 4: V_{BO} Change

vs. Junction Temperature

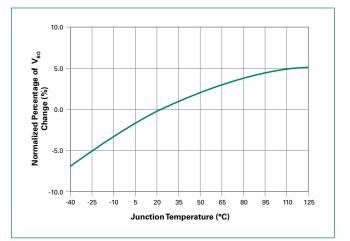
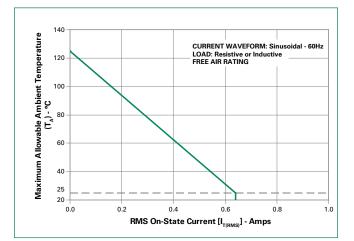


Figure 6: Maximum Allowable Ambient Temperature vs. On-State Current



Teccor[®] brand Thyristors Multipulse[™] SIDACs



Figure 7: Peak Surge Current vs Surge Current Duration

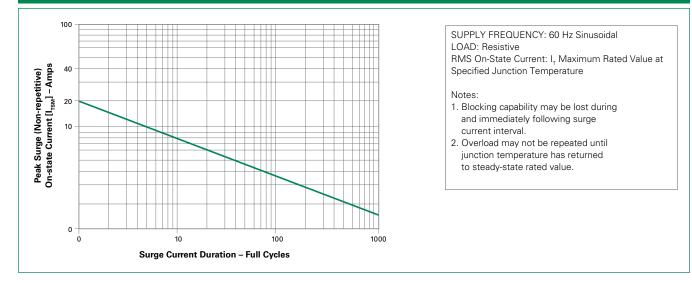


Figure 8: Typical On-State Voltage vs On-State Current

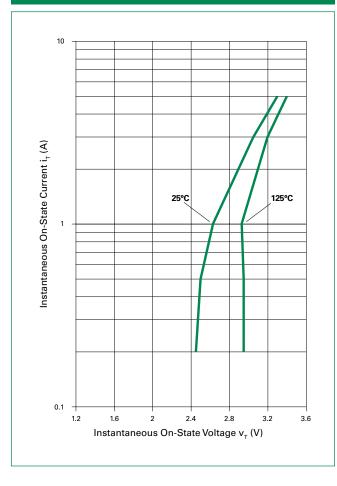
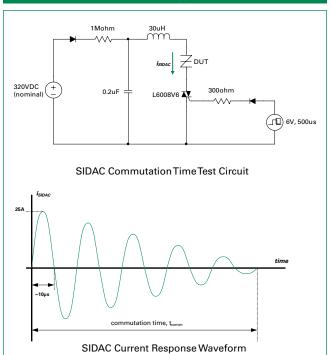


Figure 9: Multipulse[™] SIDAC t_{comm}, Commutation Time



Additional Information





Resources



Datasheet

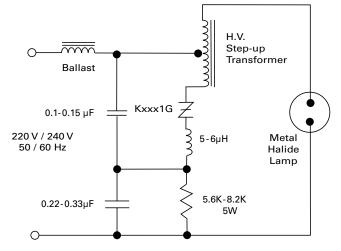
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Samples

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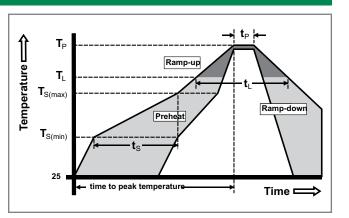
Figure 10: Typical Metal Halide Ignitor Circuit



Note: With proper component selection, this circuit will produce three pulses for ignition of metal halide lamp that requires a minimum of three pulses at 4kV magnitude and >1uSec duration each at a minimum repetition rate of 3.3kHz.

Soldering Parameters

Reflow Condition		Pb – Free assembly	
Pre Heat	-Temperature Min (T _{s(min)})	150°C	
	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ra (T _L) to pea	amp up rate (LiquidusTemp) k	5°C/second max	
T _{S(max)} to T _L - Ramp-up Rate		5°C/second max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
Reliow	-Temperature (t _L)	60 – 150 seconds	
PeakTemp	erature (T _P)	260 ^{+0/-5} °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-dov	vn Rate	5°C/second max	
Time 25°C	to peakTemperature (T _P)	8 minutes Max.	
Do not exc	ceed	280°C	





Physical Specifications			
Terminal Finish 100% Matte Tin Plated			
Body Material	UL recognized epoxy meeting flammability classification 94V-0		
Lead Material	Copper Alloy		

Package	Weight / unit (mg)		
DO-15	385		

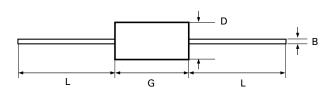
Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Overheating and surge currents are the main killers of SIDACs. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Reliability/Environmental Tests

Test	Specifications and Conditions	
High Temperature Voltage Blocking	MIL-STD-750: Method 1040, Condition A Rated V _{DRM} (VAC-peak), 125°C, 1008 hours	
Temperature Cycling	MIL-STD-750: Method 1051, 100 cycles; -40°C to 150°C, 15-minute dwell time	
Temperature / Humidity	EIA/JEDEC: JESD22-A101 1008 hours; 160V - DC: 85°C; 85% relative humidity	
High Temp Storage	MIL-STD-750: Method 1031 150°C, 1008 hours	
Low-Temp Storage	-40°C, 1008 hours	
Thermal Shock	MIL-STD-750: Method 1056 10 cycles; 0°C to 100°C; 5-minute dwell- time at each temperature; 10-sec (max) transfer time between temperature	
Autoclave	EIA/JEDEC: JESD22-A102 168 hours (121°C at 2 ATMs) and 100% RH	
Resistance to Solder Heat	MIL-STD-750: Method 2031 260°C, 10 seconds	
Solderability	ANSI/J-STD-002: Category 3, Test A	
Repetitive Surge Life Testing	Multi firings per half cycle at 60Hz in application circuit for 168 hours minimum	

Dimensions — DO-15 (G Package)



Dimension	Inches Milli		Millin	meters	
	Max	Max	Min	Max	
В	0.028	0.034	0.711	0.864	
D	0.120	0.140	3.048	3.556	
G	0.235	0.270	5.969	6.858	
L	1.000		25.400		

Product Selector

Do at Neurola ou	Switching Voltage Range		Blocking Voltage	Deckerse	
Part Number	V _{во} Minimum	V _{во} Maximum	V _{DRM}	Packages	
K2201G	200V	230V	180V	DO-15	
K2401G	220V	250V	190V	DO-15	
K2501G	240V	280V	200V	DO-15	
K3601G	340V	380V	270V	DO-15	

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Packing Options

Part Number	Package	Packing Mode	Base Quantity
Kxxx1G	DO-15	Bulk	1000
Kxxx1GRP	00-15	Tape & Reel	5000

Note: xxx = voltage

DO-15 Embossed Carrier RP Specifications

Meets all EIA RS-29-6 Standards

